



## HIGH DENSITY MOUNTING PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS

### APPROVALS

- UL recognised, File No. E91231

### DESCRIPTION

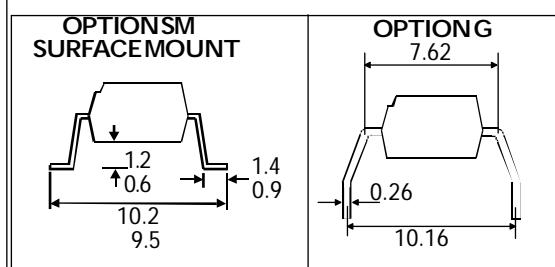
The TLP321, TLP321-2, TLP321-4 series of optically coupled isolators consist of infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

### FEATURES

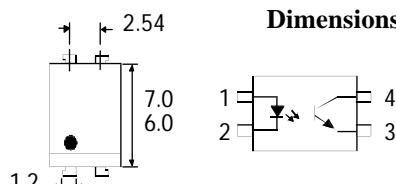
- Options :-  
10mm lead spread - add G after part no.  
Surface mount - add SM after part no.  
Tape&reel - add SMT&R after part no.
- High Current Transfer Ratio ( 50% min)
- High Isolation Voltage (5.3kV<sub>RMS</sub>, 7.5kV<sub>PK</sub>)
- High BV<sub>CEO</sub> ( 80Vmin )
- All electrical parameters 100% tested
- Custom electrical selections available

### APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

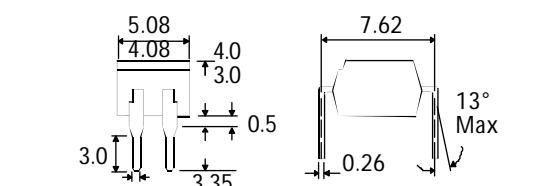


TLP321

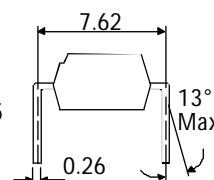
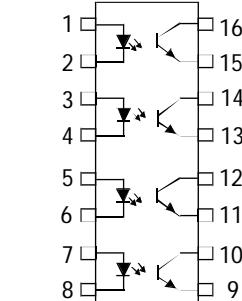
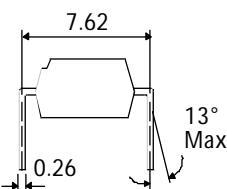
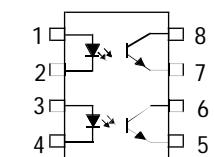
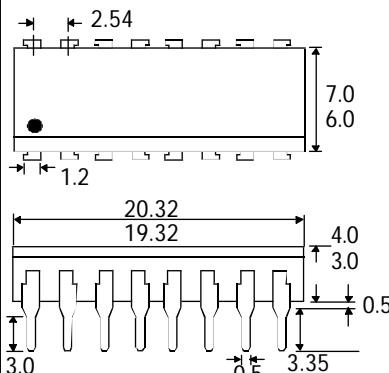


Dimensions in mm

TLP321-2



TLP321-4



**ISOCOM COMPONENTS LTD**  
Unit 25B, Park View Road West,  
Park View Industrial Estate, Brenda Road  
Hartlepool, Cleveland, TS25 1YD  
Tel: (01429) 863609 Fax : (01429) 863581

**ISOCOM INC**  
720 E., Park Boulevard, Suite 104,  
Plano, TX 75074 USA  
Tel: (972) 423-5521  
Fax: (972) 422-4549

**ABSOLUTE MAXIMUM RATINGS**  
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 125°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

**INPUT DIODE**

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	70mW

**OUTPUT TRANSISTOR**

Collector-emitter Voltage BV <sub>CEO</sub>	80V
Emitter-collector Voltage BV <sub>ECO</sub>	6V
Power Dissipation	150mW

**POWER DISSIPATION**

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

**ELECTRICAL CHARACTERISTICS ( T<sub>A</sub> = 25°C Unless otherwise noted )**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V <sub>F</sub> ) Reverse Voltage (V <sub>R</sub> ) Reverse Current (I <sub>R</sub> )	1.0 5	1.15	1.3 10	V V μA	I <sub>F</sub> = 10mA I <sub>R</sub> = 10μA V <sub>R</sub> = 5V
Output	Collector-emitter Breakdown (BV <sub>CEO</sub> ) ( Note 2 ) Emitter-collector Breakdown (BV <sub>ECO</sub> ) Collector-emitter Dark Current (I <sub>CEO</sub> )	80 6			V V nA	I <sub>C</sub> = 0.5mA I <sub>E</sub> = 100μA V <sub>CE</sub> = 48V
Coupled	Current Transfer Ratio (CTR) (Note 2) TLP321, TLP321-2, TLP321-4 CTR selection available GB BL GB Collector-emitter Saturation Voltage V <sub>CE (SAT)</sub> GB Input to Output Isolation Voltage V <sub>ISO</sub> Input-output Isolation Resistance R <sub>ISO</sub> Rise Time tr Fall Time tf Turn-on Time ton Turn-off Time toff	50 100 200 30 5300 7500 5x10 <sup>10</sup>		600 600 600 0.4 0.4 V V V <sub>RMS</sub> V <sub>PK</sub>	% % % % % Ω μs μs μs μs	5mA I <sub>F</sub> , 5V V <sub>CE</sub> 1mA I <sub>F</sub> , 0.4V V <sub>CE</sub> 8mA I <sub>F</sub> , 2.4mA I <sub>C</sub> 1mA I <sub>F</sub> , 0.2mA I <sub>C</sub> See note 1 V <sub>IO</sub> = 500V (note 1) V <sub>CC</sub> = 10V , I <sub>C</sub> = 2mA, R <sub>L</sub> = 100Ω

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

